

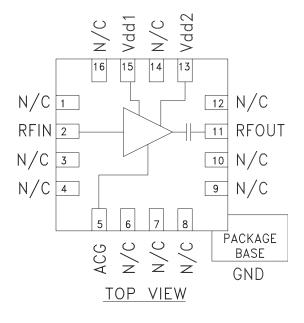


#### **Typical Applications**

The HMC375LP3 / HMC375LP3E is ideal for basestation receivers:

- GSM, GPRS & EDGE
- CDMA & W-CDMA
- DECT

#### **Functional Diagram**



# HMC375LP3 / 375LP3E

## GaAs PHEMT MMIC LOW NOISE AMPLIFIER, 1.7 - 2.2 GHz

#### Features

Noise Figure: 0.9 dB Output IP3: +34 dBm Gain: 17 dB Very Stable Gain vs. Supply & Temperature Single Supply: +5V @ 136 mA 50 Ohm Matched Output

#### **General Description**

The HMC375LP3 & HMC375LP3E high dynamic range GaAs PHEMT MMIC Low Noise Amplifiers are ideal for GSM & CDMA cellular basestation front-end receivers operating between 1.7 and 2.2 GHz. This LNA has been optimized to provide 0.9 dB noise figure, 17 dB gain and +33 dBm output IP3 from a single supply of +5V @ 136mA. Input and output return losses are 14 dB typical with the LNA requiring minimal external components to optimize the RF input match, RF ground and DC bias. For applications which require improved noise figure, please see the HMC618LP3(E).

#### Electrical Specifications, $T_{A} = +25^{\circ} C$ , Vs = +5V

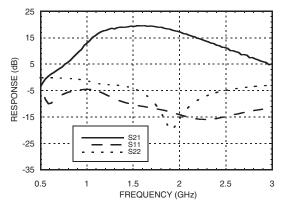
Parameter	Min.	Тур.	Max.	Min.	Тур.	Max.	Min.	Тур.	Max.	Min.	Тур.	Max.	Units
Frequency Range	1.8 - 1.9		1.9 - 2.0		2.0 - 2.1		2.1 - 2.2		GHz				
Gain	16.5	18.5		15.5	17.5		15	17		13	15		dB
Gain Variation Over Temperature		0.014	0.021		0.014	0.021		0.014	0.021		0.014	0.021	dB/°C
Noise Figure		1.0	1.35		0.95	1.2		0.9	1.2		0.9	1.3	dB
Input Return Loss		12			13			14			15		dB
Output Return Loss		13			16			11			8		dB
Reverse Isolation		35			34			34			34		dB
Output Power for 1dB Compression (P1dB)	16	18.5		16	18.5		15	18		14.5	17.5		dBm
Saturated Output Power (Psat)		19.5			19.5			19.5			19.5		dBm
Output Third Order Intercept (IP3) (-20 dBm Input Power per tone, 1 MHz tone spacing)		34			33.5			33			32.5		dBm
Supply Current (Idd)		136			136			136			136		mA

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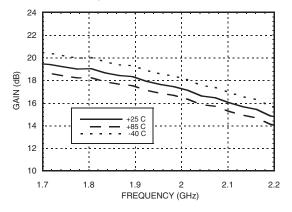




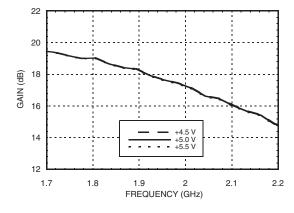
#### Broadband Gain & Return Loss



Gain vs. Temperature

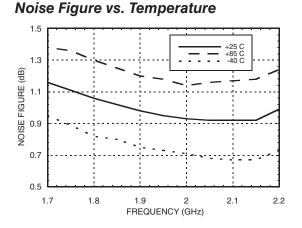


Gain vs. Vdd

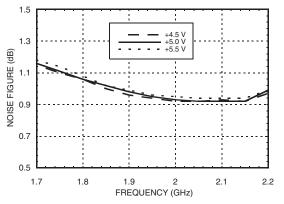


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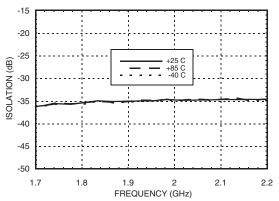
# GaAs PHEMT MMIC LOW NOISE AMPLIFIER, 1.7 - 2.2 GHz







#### **Reverse Isolation vs. Temperature**



AMPLIFIERS - LOW NOISE - SMT

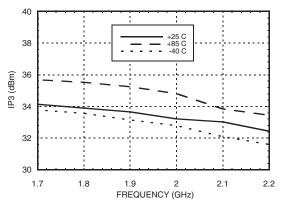
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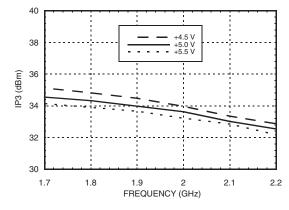


# Input Return Loss vs. Temperature

Output IP3 vs. Temperature

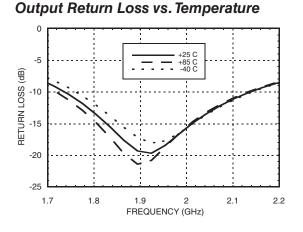


Output IP3 vs. Vdd

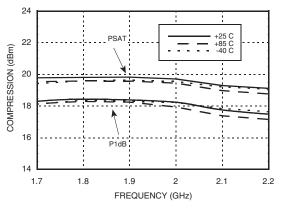


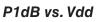
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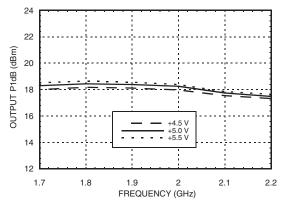
## GaAs PHEMT MMIC LOW NOISE AMPLIFIER, 1.7 - 2.2 GHz



P1dB & PSAT vs. Temperature







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#### Absolute Maximum Ratings

Drain Bias Voltage (Vdd1, Vdd2)	+8.0 Vdc		
RF Input Power (RFIN)(Vs = +5.0 Vdc)	+10 dBm		
Channel Temperature	150 °C		
Continuous Pdiss (T = 85 °C) (derate 15.6 mW/°C above 85 °C)	1.015 W		
Thermal Resistance (channel to ground paddle)	64.1 °C/W		
Storage Temperature	-65 to +150 °C		
Operating Temperature	-40 to +85 °C		

# HMC375LP3 / 375LP3E

## GaAs PHEMT MMIC LOW NOISE AMPLIFIER, 1.7 - 2.2 GHz

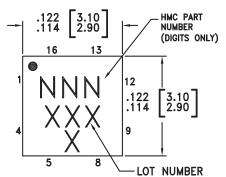
#### Typical Supply Current vs. Vdd

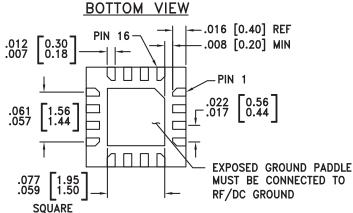
Vdd (Vdc)	ldd (mA)		
+4.5	135		
+5.0	136		
+5.5	137		

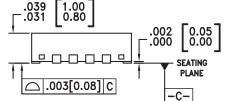


ELECTROSTATIC SENSITIVE DEVICE OBSERVE HANDLING PRECAUTIONS

#### **Outline Drawing**







#### NOTES:

1. LEADFRAME MATERIAL: COPPER ALLOY

2. DIMENSIONS ARE IN INCHES [MILLIMETERS]

- 3. LEAD SPACING TOLERANCE IS NON-CUMULATIVE
- 4. PAD BURR LENGTH SHALL BE 0.15mm MAXIMUM.
- PAD BURR HEIGHT SHALL BE 0.05mm MAXIMUM.
- 5. PACKAGE WARP SHALL NOT EXCEED 0.05mm.
- 6. ALL GROUND LEADS AND GROUND PADDLE MUST BE SOLDERED TO PCB RF GROUND.
- 7. REFER TO HITTITE APPLICATION NOTE FOR SUGGESTED LAND PATTERN.

#### Package Information

Part Number	Package Body Material	Lead Finish	MSL Rating	Package Marking <sup>[3]</sup>	
HMC375LP3	Low Stress Injection Molded Plastic	Sn/Pb Solder	MSL1 <sup>[1]</sup>	375 XXXX	
HMC375LP3E	RoHS-compliant Low Stress Injection Molded Plastic	100% matte Sn	MSL1 <sup>[2]</sup>	<u>375</u> XXXX	

[1] Max peak reflow temperature of 235 °C

[2] Max peak reflow temperature of 260 °C

[3] 4-Digit lot number XXXX

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HMC375LP3 / 375LP3E

## GaAs PHEMT MMIC LOW NOISE AMPLIFIER, 1.7 - 2.2 GHz

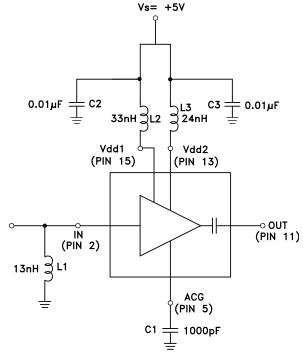


#### **Pin Descriptions**

Pin Number	Function	Description	Interface Schematic
1, 3, 4, 6-10, 12, 14, 16	N/C	No connection necessary. These pins may be connected to RF/DC ground.	
2	RFIN	This pin is matched to 50 Ohms with a 13 nH inductor to ground. See Application Circuit.	RFIN O
5	ACG	AC Ground - An external capacitor of 0.01μF to ground is required for low frequency bypassing. See Application Circuit for further details.	ACG O
11	RFOUT	This pin is AC coupled and matched to 50 Ohms.	
13,15	Vdd2, Vdd1	Power supply voltage. Choke inductor and bypass capacitor are required. See application circuit.	ACG O
	GND	Package bottom must be connected to RF/DC ground.	

v03.0610

#### **Application Circuit**



Note: L1, L2, L3 and C1 should be located as close to pins as possible.

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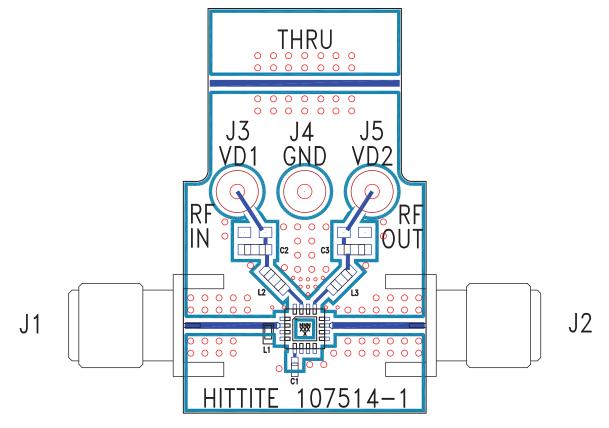


HMC375LP3 / 375LP3E

### GaAs PHEMT MMIC LOW NOISE AMPLIFIER, 1.7 - 2.2 GHz



#### **Evaluation PCB**



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#### List of Materials for Evaluation PCB 107726 [1]

Item	Description	
J1 - J2	PCB Mount SMA RF Connector	
J3 - J4	DC Pin	
C1	1000 pF Capacitor, 0402 Pkg.	
C2, C3	10000 pF Capacitor, 0603 Pkg.	
L1	13nH Inductor, 0402 Pkg.	
L2	33nH Inductor, 0603 Pkg.	
L3	24nH Inductor, 0402 Pkg.	
U1	HMC375LP3 / HMC375LP3E Amplifier	
PCB [2]	107514 Evaluation PCB	

[1] Reference this number when ordering complete evaluation PCB

[2] Circuit Board Material: Rogers 4350

The circuit board used in the application should use RF circuit design techniques. Signal lines should have 50 Ohm impedance while the package ground leads and exposed paddle should be connected directly to the ground plane similar to that shown. A sufficient number of via holes should be used to connect the top and bottom ground planes. The evaluation circuit board shown is available from Hittite upon request.

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